NSN 5961-01-159-3166

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View Online at https://aerobasegroup.com/nsn/5961-01-159-3166 **Inclosure Material:** Metal **Overall Length:** 0.070 inches **Overall Diameter:** 0.110 inches **Internal Configuration:** Junction contact **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 25.0 collector to base voltage/static/emitter open and 16.0 collector to emitter voltage/static/base open and 1.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 35.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 300.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 4 ribbon and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: